

VOLTAGE CHART

		D.C. VOLTAGE														R.F. VOLTAGE														
MJ PIN	1		2		3		4		5		6		7		1		2		3		4		5		6		7			
	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T		
1	E	E	E	E	E	E	E	E	E	E	E	E	0	0	E	E	E	E	E	E	E	E	E	E	E	E	E	E	3180KHz 85dB	—
2	E	E	E	E	0	0	0	0	0	0	-70	-55	E	E	E	E	—	—	—	—	—	—	—	—	—	—	—	—	E	E
3	6.0	6.0	0	0	13.0	12.5	0	0	0.7	0.7	-18	0	E	E	3	3	3180KHz 95dB	—	—	—	—	—	—	—	—	—	—	E	E	
4	0.5	0.5	E	E	0	0	0	0	8.5	8.5	-20	-3.5	0	0	2	2	E	E	—	—	—	—	—	—	—	—	—	3180KHz 85dB	—	
5	5.5	5.5	0	0	0	0	0	0	6.0	6.0	-150	-140	0	13.0	—	—	0	0	0.6	0	—	—	—	—	—	—	—	—	—	
6	6.0	6.0	E	E	0	0	E	E	0	0	170	170	0	0	—	—	E	E	—	—	E	E	1	1	—	—	—	—	—	
7	E	E	13.0	12.5	E	E	0	0	E	E	2.7	2.7	13.5	13.5	E	E	—	—	E	E	—	—	E	E	—	—	—	—	—	
8	0	0	E	E	0	11.5	0	0	0	0	0.6	2.7	1.0	1.0	14MHz 48dB	—	E	E	—	—	—	—	—	—	—	—	—	—	—	
9	8.0	13.0	12.0	0	9.0	9.0	9.0	9.0	0	0	12.5	0	E	E	—	—	—	—	—	—	—	—	—	—	—	—	—	E	E	
10	0	11.5	E	E	6.5	0.35	1.5	1.5	13.0	12.5	0	11.5	E	E	—	—	E	E	3180KHz 70dB	—	—	—	—	—	—	—	—	E	E	
11	13.0	12.5	0	0	13.0	12.5	E	E	0	0	2.5	2.5	—	—	14250 46dB	1	0.08	0.06	—	—	E	E	—	—	—	—	—	—	—	
12	12.5	0	E	E	0.7	0.7	9.0	9.0	6.6	0.3	13.5	13.0	—	—	—	—	E	E	—	—	—	—	—	—	0.1	—	—	—	—	
13	12.0	0	0	11.5	8.0	13.0	0	0	12.5	0	6.0	6.0	—	—	—	0.06	—	—	—	—	—	—	—	—	—	—	—	—	—	
14	13.0	12.5	—	E	E	E	6.0	6.0	12.5	0.3	13.0	12.5	—	—	—	—	—	E	E	E	—	—	—	—	—	—	—	—	—	
15	0	0	13.0	12.5	0	0	13.0	12.5	—	—	0	0	—	—	0.3	0.8	5720KHz 66dB	0.3	3180KHz 83dB	0.06	—	—	—	—	—	—	—	—	—	—
16	0	11.5	13.0	12.5	0	0	13.0	12.5	—	—	0	0	—	—	—	—	5720KHz 56dB	0.1	—	—	—	—	—	—	—	—	—	—	—	
17	13.0	12.5	E	E	0	0	0	0	—	—	0	0	—	—	5720KHz 70dB	0.3	E	E	3180KHz 78dB	0.03	—	—	—	—	—	—	—	—	—	
18	E	E	E	E	0	0	E	E	—	—	E	E	—	—	E	E	E	E	—	—	E	E	—	—	E	E	—	—	—	
19	—	—	—	—	13.0	12.5	E	E	—	—	—	—	—	—	—	—	—	—	—	—	E	E	—	—	—	—	—	—	—	
20	—	—	—	—	12.5	0	E	E	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	
21	—	—	—	—	6.0	6.0	E	E	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	—	
22	—	—	—	—	E	E	0	0	—	—	—	—	—	—	—	—	—	—	E	E	—	—	—	—	—	—	—	—	—	

VALUES ARE IN VOLTS D.C.
R: RECEIVE, T: TRANSMIT

MODE: USB, BAND: 20M, R: RECEIVE, T: TRANSMIT
VALUES WITHOUT ANY UNIT ARE IN VOLTS R.M.S.
VALUES WITH DB ARE SIGNAL GENERATOR OUTPUT LEVELS TO PRODUCE S-9.
VALUES GIVEN UNDER THE COLUMN T ARE SIGNAL LEVELS TO PRODUCE 100W OUTPUT POWER MODULATED BY 1KHz MIC INPUT.

RESISTANCE CHART

MJ PINNO. \ NO.	1	2	3	4	5	6	7
1	E	E	E	E	E	E	∞
2	E	E	15 0	30K	0	10K	E
3	300	0	10	0	∞	4K	E
4	3K	E	∞	※	10 K	10K	0
5	300	∞	0	∞	200	30K	0
6	200	E	1K	E	5	50K	0
7	E	10	E	0	E	3K	10
8	0	E	0	1K	5K	6K	100K
9	2.5K	12 0	10K	10 K	1K	120	E
10	※	E	3K	50K	10	0	E
11	100	∞	10	E	1M	3K	—
12	120	E	1K	50K	3K	10	—
13	120	0	3K	∞	1.2K	200	—
14	10	※	E	200	700	10	—
15	0	10 0	∞	10	—	50K	—
16	0	10 0	∞	10	—	0	—
17	100	E	∞	※	—	∞	—
18	E	E	∞	∞	—	E	—
19	—	—	10	※	—	—	—
20	—	—	120	E	—	—	—
21	—	—	200	E	—	—	—
22	—	—	E	※	—	—	—

VALUES ARE IN OHMS.

Order Instruction:

Parts number is independent for each unit, except T-transformers and T-inductors, therefore it is requested to specify parts number together with unit classification as following example.

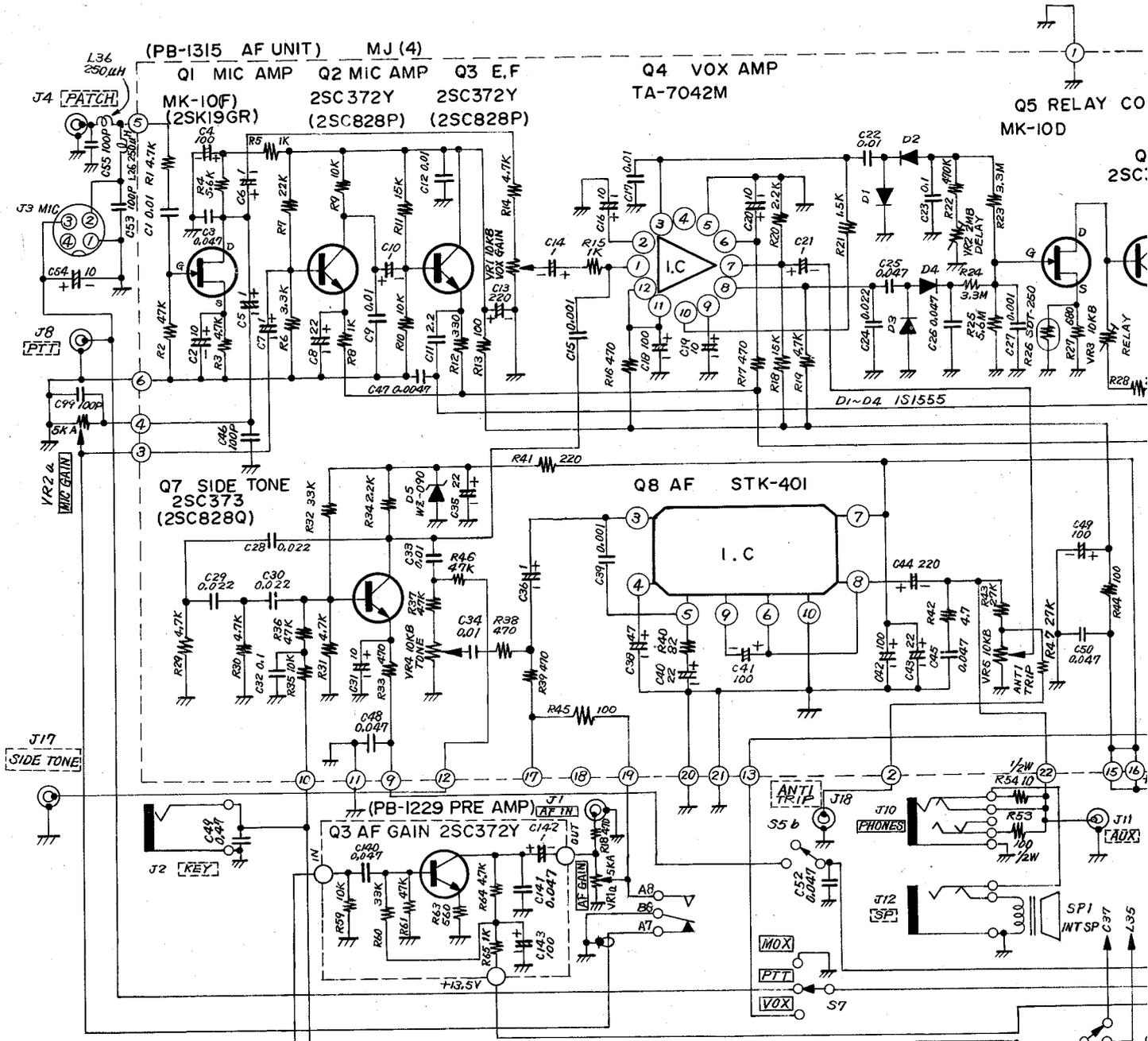
No. 1 RF Unit R1 100K ohm $\frac{1}{4}$ W ※ VALUE IS NOMINAL

RF UNIT				C-CAPACITOR			
PRINTED CIRCUIT BOARD PB-1181(A~Z)				DIPPED MICA			
Q-FET & TRANSISTOR				6, 19	50 WV	20PF	$\pm 10\%$
4	TR.	2SC372Y		1, 8	50 WV	40PF	$\pm 10\%$
5	TR.	2SC373		8	50 WV	100PF	$\pm 10\%$
3	TR.	2SC784R		2	50 WV	470PF	$\pm 10\%$
2	FET	2SK19GR		CERAMIC DISC			
1	FET	3SK40M		7	50 WV	0.001 μ F	$\pm 80\%$ $- 20\%$
D-DIODE				3~5, 9, 11, 13	50 WV	0.01 μ F	$\pm 80\%$ $- 20\%$
1, 2	Si	1S1555		17	50 WV	0.047 μ F	$\pm 80\%$ $- 20\%$
R-RESISTOR				CERAMIC FEED THRU			
CARBON FILM				14~16	500 WV	0.001 μ F	$\pm 100\%$ 0%
22	$\frac{1}{4}$ W	56 Ω	$\pm 10\%$	ELECTROLYTIC			
23	$\frac{1}{4}$ W	100 Ω	$\pm 10\%$	18	16 WV	1 μ F	
16, 24	$\frac{1}{4}$ W	220 Ω	$\pm 10\%$	TC-TRIMMER CAPACITOR			
6	$\frac{1}{4}$ W	330 Ω	$\pm 10\%$	CERAMIC			
10, 19	$\frac{1}{4}$ W	470 Ω	$\pm 10\%$	1~3	ECVIZW50P32	50 PF	
11	$\frac{1}{4}$ W	560 Ω	$\pm 10\%$	L-INDUCTOR			
9, 13	$\frac{1}{4}$ W	1 K Ω	$\pm 10\%$	1	BPF-A		
7	$\frac{1}{4}$ W	1.8 K Ω	$\pm 10\%$	2	BPF-B		
8	$\frac{1}{4}$ W	2.2 K Ω	$\pm 10\%$	3	BPF-C		
17, 20	$\frac{1}{4}$ W	3.3 K Ω	$\pm 10\%$	34	RF CHOKE	1.95 μ H	
21	$\frac{1}{4}$ W	8.2 K Ω	$\pm 10\%$	4, 8	RF CHOKE	250 μ H	
14, 18	$\frac{1}{4}$ W	15 K Ω	$\pm 10\%$	T-TRANSFORMER & INDUCTOR			
2	$\frac{1}{4}$ W	22 K Ω	$\pm 10\%$	112A	IF TRANSFORMER		
4	$\frac{1}{4}$ W	82 K Ω	$\pm 10\%$	113	TRAP COIL		
1, 3, 5, 12	$\frac{1}{4}$ W	100 K Ω	$\pm 10\%$	X-CRYSTAL			
VR-VARIABLE RESISTOR				1	HC-18/U	6360 KHz	
1	TR-11R	5K Ω B		IF UNIT			
C-CAPACITOR				PRINTED CIRCUIT BOARD PB-1183(A~Z)			
DIPPED MICA				Q-FET, IC & TRANSISTOR			
17	50 WV	6PF	± 0.5 PF	2	TR.	2SC784R	
5	50 WV	50PF	$\pm 10\%$	4, 5	TR.	2SC828Q	
1, 11	50 WV	100PF	$\pm 10\%$	3	IC	CA3053	
CERAMIC DISC				1	FET	2SK19GR	
3	50 WV	0.001 μ F	$\pm 80\%$ $- 20\%$	D-DIODE			
2, 4, 7~10, 12~16,	50 WV	0.01 μ F	$\pm 80\%$ $- 20\%$	1~5, 7~11	Ge.	1S1007	
6, 18	50 WV	0.047 μ F	$\pm 80\%$ $- 20\%$	6	Si.	1S1555	
ELECTROLYTIC				12	Zener	WZ-110	
19	16 WV	47 μ F		R-RESISTOR			
L-INDUCTOR				CARBON FILM			
1, 2	RF CHOKE	1mH		2, 13, 16	$\frac{1}{4}$ W	100 Ω	$\pm 10\%$
MIXER UNIT				23	$\frac{1}{4}$ W	220 Ω	$\pm 10\%$
PRINTED CIRCUIT BOARD PB-1082(A~Z) PB-1180(A~Z)				20	$\frac{1}{4}$ W	470 Ω	$\pm 10\%$
Q-FET & TRANSISTOR				12, 15, 19	$\frac{1}{4}$ W	1 K Ω	$\pm 10\%$
1	TR.	2SC372Y		3, 14	$\frac{1}{4}$ W	2.2 K Ω	$\pm 10\%$
2	FET	3SK40M		8, 9, 22	$\frac{1}{4}$ W	3.3 K Ω	$\pm 10\%$
D-DIODE				11	$\frac{1}{4}$ W	3.9 K Ω	$\pm 10\%$
1	Si.	1S1555		4, 5	$\frac{1}{4}$ W	5.6 K Ω	$\pm 10\%$
R-RESISTOR				17, 24, 25, 27	$\frac{1}{4}$ W	10 K Ω	$\pm 10\%$
CARBON FILM				10	$\frac{1}{4}$ W	27 K Ω	$\pm 10\%$
12	$\frac{1}{4}$ W	10 Ω	$\pm 10\%$	1, 18, 21	$\frac{1}{4}$ W	100 K Ω	$\pm 10\%$
5, 7	$\frac{1}{4}$ W	100 Ω	$\pm 10\%$	CARBON COMPOSITION			
13	$\frac{1}{4}$ W	470 Ω	$\pm 10\%$	26	$\frac{1}{4}$ W	1 M Ω	$\pm 10\%$
3, 16, 17	$\frac{1}{4}$ W	1 K Ω	$\pm 10\%$	6, 7	$\frac{1}{2}$ W	100 Ω	$\pm 10\%$
2	$\frac{1}{4}$ W	4.7 K Ω	$\pm 10\%$	VR-VARIABLE RESISTOR			
14, 15	$\frac{1}{4}$ W	5.6 K Ω	$\pm 10\%$	1	TR12R	500 Ω B	
10	$\frac{1}{4}$ W	10 K Ω	$\pm 10\%$	2	TR11R	500 Ω B	
4, 6	$\frac{1}{4}$ W	15 K Ω	$\pm 10\%$	C-CAPACITOR			
11	$\frac{1}{4}$ W	22 K Ω	$\pm 10\%$	DIPPED MICA			
1	$\frac{1}{4}$ W	27 K Ω	$\pm 10\%$	1, 24, 25	50 WV	100PF	$\pm 10\%$
8	$\frac{1}{4}$ W	100 K Ω	$\pm 10\%$				
9	$\frac{1}{4}$ W	220 K Ω	$\pm 10\%$				

15, 22	50WV	150PF ±10%	15, 27, 39	50WV	0.001μF ±20%
11, 17	50WV	470PF ±10%	1, 9, 12, 17, 22, 33, 34	50WV	0.01 μF ±20%
CERAMIC DISC			24, 28~30	50WV	0.022μF ±20%
26~28	50WV	0.001μF	3, 25, 26, 45, 48, 50	50WV	0.047μF ±20%
2~6, 9, 10, 12, 13, 18, 20,	50WV	0.01 μF	23, 32	50WV	0.1 μF ±20%
21, 23, 31~34			11	50WV	2.2 μF ±20%
7, 8, 14, 16, 19, 35	50WV	0.047μF	ELECTROLYTIC		
			5~7, 10, 14, 21, 36	16WV	1μF
			2, 16, 19, 20, 31	16WV	10μF
PLASTIC FILM			8, 35, 40, 43	16WV	22μF
29	50WV	0.47 μF ±20%	38	16WV	47μF
ELECTROLYTIC			4, 18, 41, 42, 49	16WV	100μF
30	16WV	10μF	13, 44	16WV	220μF
L-INDUCTOR			MOD. & OSC UNIT		
1~4	RF CHOKE 250μH		PRINTED CIRCUIT BOARD PB-1184(A~Z)		
T-TRANSFORMER & INDUCTOR			Q-FET & TRANSISTOR		
108	IF TRANSFORMER		2, 3, 5, 6	TR.	2SC372Y
109	IF TRANSFORMER(DETECTOR)		4	TR.	2SC828P
XF-CRYSTAL FILTER			1	FET.	MK-10D
1	XF-32A SSB		D-DIODE		
2	XF-30C CW(OPTION)		1~4	Ge.	1S1007
AF UNIT			R-RESISTOR		
PRINTED CIRCUIT BOARD PB-1315(A~Z)			CARBON FILM		
Q-FET, IC & TRANSISTOR			18	¼W	100 Ω ±10%
2, 3	TR.	2SC372Y	1, 3	¼W	150 Ω ±10%
6, 7	TR.	2SC373	19	¼W	180 Ω ±10%
5	FET	MK-10D	2, 21, 30	¼W	470 Ω ±10%
1	FET	2SK19GR	9~11, 14, 24, 28	¼W	1 KΩ ±10%
8	IC	STK401	20	¼W	1.5KΩ ±10%
4	IC	TA7042M	6, 8	¼W	2.2KΩ ±10%
D-DIODE			12, 15, 16, 22, 25, 26, 29	¼W	4.7KΩ ±10%
1~4	Si.	1S1555	32	¼W	10 KΩ ±10%
5	Zener	WZ-090	33	¼W	15 KΩ ±10%
R-RESISTOR			13, 17, 23, 27	¼W	22 KΩ ±10%
CARBON FILM			7	¼W	33 KΩ ±10%
42	¼W	4.7Ω ±10%	4	¼W	100 KΩ ±10%
40	¼W	82 Ω ±10%	VR-VARIABLE RESISTOR		
13, 44, 45	¼W	100 Ω ±10%	1	TRIIR	500ΩB
41	¼W	220 Ω ±10%	2	TRIIR	5KΩB
12	¼W	330 Ω ±10%	C-CAPACITOR		
16, 17, 33, 38, 39	¼W	470 Ω ±10%	DIPPED MICA		
27	¼W	680 Ω ±10%	20, 28, 30	50WV	30PF ±10%
5, 8, 15	¼W	1 KΩ ±10%	19, 27, 32	50WV	40PF ±10%
21	¼W	1.5KΩ ±10%	38	50WV	50PF ±10%
20, 28, 34	¼W	2.2KΩ ±10%	5, 10, 37	50WV	100PF ±10%
6	¼W	3.3KΩ ±10%	CERAMIC DISC		
1, 3, 14, 19, 29~31	¼W	4.7KΩ ±10%	4	50WV	150PF ±10%
4	¼W	5.6KΩ ±10%	21	50WV	300PF ±10%
9, 10, 35	¼W	10 KΩ ±10%	23, 36	50WV	1000PF ±10%
11, 18	¼W	15 KΩ ±10%	ELECTROLYTIC		
7	¼W	22 KΩ ±10%	31	50WV	0.001μF
43, 47	¼W	27 KΩ ±10%	2, 8, 9, 13, 17, 18, 24,	50WV	0.01 μF
32	¼W	33 KΩ ±10%	26, 29, 33		
2, 36, 37, 46	¼W	47 KΩ ±10%	6, 11, 22, 25, 34	50WV	0.047μF
22	¼W	470 KΩ ±10%	PLASTIC FILM		
CARBON COMPOSITION			12	50WV	0.22 μF ±20%
23, 24	¼W	3.3MΩ ±10%	ELECTROLYTIC		
25	¼W	5.6MΩ ±10%	15	16WV	100μF
26	THERMISTOR SDT-250		TC-TRIMMER CAPACITOR		
VR-VARIABLE RESISTOR			CERAMIC		
3, 4	TRIIR	10KΩB	2~4	ECV1ZW20P40	20PF
1, 5	VI60KRZ-1	10KΩB	1, 5, 6	ECV1ZW50P40	50PF
2	VI60KRZ-1	2MΩB	L-INDUCTOR		
C-CAPACITOR			5	RF CHOKE 10μH	
DIPPED MICA			2~4, 6, 7	RF CHOKE 22μH	
46	50WV	100PF ±10%	8, 9	RF CHOKE 250μH	
PLASTIC FILM					
47	50WV	0.0047μF ±20%			

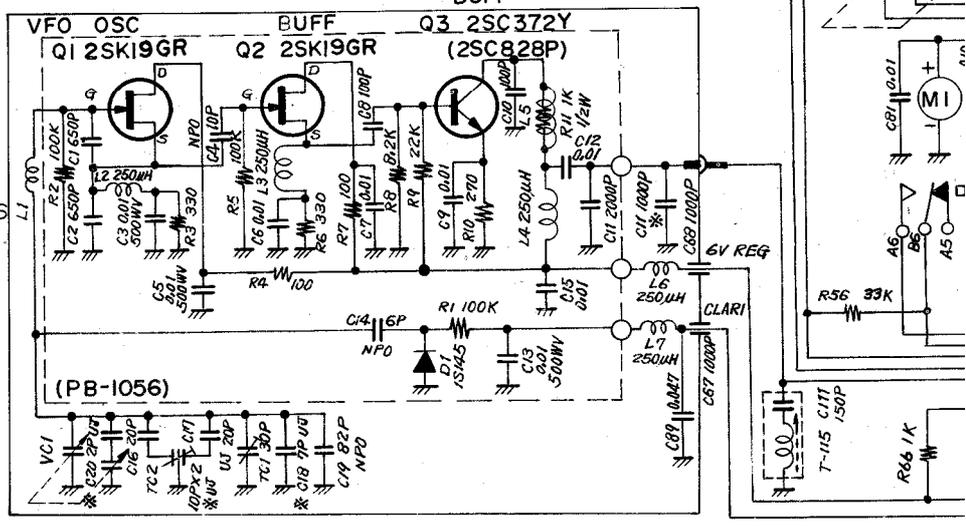
T-TRANSFORMER			D-DIODE		
110	IF TRANSFORMER		1~3	Si	1S1555
X-CRYSTAL			4	Zener	WZ090
1	HC-6/U 3178. 5KHz(USB)		R-RESISTOR		
2	HC-6/U 3181. 5KHz(LSB)		CARBON FILM		
3	HC-6/U 3179. 3KHz(CW/AM)		4, 13	$\frac{1}{4}W$	100 $\Omega \pm 10\%$
REG. & CALIB UNIT			16	$\frac{1}{4}W$	330 $\Omega \pm 10\%$
PRINTED CIRCUIT BOARD PB-1314(A~Z)			3	$\frac{1}{4}W$	560 $\Omega \pm 10\%$
Q-TRANSISTOR			6, 8, 12, 19	$\frac{1}{4}W$	1 K $\Omega \pm 10\%$
6	TR.	2SC372Y	18	$\frac{1}{4}W$	1.5K $\Omega \pm 10\%$
1~4	TR.	2SC735Y	15	$\frac{1}{4}W$	2.2K $\Omega \pm 10\%$
5	TR.	2SD313	9, 11, 21, 22	$\frac{1}{4}W$	3.3K $\Omega \pm 10\%$
D-DIODE			1	$\frac{1}{4}W$	4.7K $\Omega \pm 10\%$
2	Zener	1S993	2, 10	$\frac{1}{4}W$	22 K $\Omega \pm 10\%$
1, 5, 6	Si	1S1555	5, 7, 14, 17, 20	$\frac{1}{4}W$	100 K $\Omega \pm 10\%$
3	Zener	WZ-090	VR-VARIABLE RESISTOR		
R-RESISTOR			1	TRIIR	10K ΩB
CARBON FILM			C-CAPACITOR		
3, 10	$\frac{1}{4}W$	100 $\Omega \pm 10\%$	DIPPED MICA		
22	$\frac{1}{4}W$	220 $\Omega \pm 10\%$	1	50WV	3PF $\pm 0.5PF$
17, 19,	$\frac{1}{4}W$	330 $\Omega \pm 10\%$	13	50WV	6PF $\pm 1PF$
26	$\frac{1}{4}W$	470 $\Omega \pm 10\%$	3, 9, 16, 18	50WV	30PF $\pm 10\%$
18	$\frac{1}{4}W$	1 K $\Omega \pm 10\%$	12	50WV	50PF $\pm 10\%$
12	$\frac{1}{4}W$	1.5K $\Omega \pm 10\%$	11, 21, 22	50WV	100PF $\pm 10\%$
20	$\frac{1}{4}W$	2.2K $\Omega \pm 10\%$	2, 4, 8, 15	50WV	130PF $\pm 10\%$
4, 7, 11	$\frac{1}{4}W$	4.7K $\Omega \pm 10\%$	CERAMIC DISC		
1, 8, 13, 15, 24	$\frac{1}{4}W$	10 K $\Omega \pm 10\%$	5, 10, 14, 17, 19, 20, 24,	50WV	0.01 $\mu F \pm 80\%$
25	$\frac{1}{4}W$	15 K $\Omega \pm 10\%$	25, 28, 29		
5	$\frac{1}{4}W$	27 K $\Omega \pm 10\%$	6, 26, 27	50WV	0.047 $\mu F \pm 80\%$
6	$\frac{1}{4}W$	33 K $\Omega \pm 10\%$	ELECTROLYTIC		
14	$\frac{1}{4}W$	47 K $\Omega \pm 10\%$	7, 23	16WV	1 μF
2, 9	$\frac{1}{4}W$	100 K $\Omega \pm 10\%$	TC-TRIMMER CAPACITOR		
CARBON COMPOSITION			CERAMIC		
16	2W	6.8K $\Omega \pm 10\%$	1~4	ECV1ZW50P40	50PF
VR-VARIABLE RESISTOR			L-INDUCTOR		
4	TRIIR	500 ΩB	2	RF CHOKE	250 μH
3	TRIIR	1K ΩB	1, 3~5	RF CHOKE	1mH
1	TRIIR	10K ΩB	T-TRANSFORMER		
2	V160KRZ-1	10K ΩB	116~119	IF TRANSFORMER R124129	
C-CAPACITOR			FIX UNIT		
DIPPED MICA			PRINTED CIRCUIT BOARD PB-1344(A~Z)		
5, 6, 21	50WV	30PF $\pm 10\%$	Q-FET		
9	50WV	40PF $\pm 10\%$	1	FET	MK10E
20	50WV	50PF $\pm 10\%$	D-DIODE		
2	50WV	100PF $\pm 10\%$	1	Varactor	1S145
1	50WV	250PF $\pm 10\%$	R-RESISTOR		
7, 8	50WV	1000PF $\pm 10\%$	CARBON FILM		
3	50WV	2000PF $\pm 10\%$	2	$\frac{1}{4}W$	56 $\Omega \pm 10\%$
CERAMIC DISC			3	$\frac{1}{4}W$	100 $\Omega \pm 10\%$
4, 19	50WV	0.01 $\mu F \pm 80\%$	1, 4	$\frac{1}{4}W$	100K $\Omega \pm 10\%$
PLASTIC FILM			C-CAPACITOR		
24	250WV	0.047 $\mu F \pm 20\%$	DIPPED MICA		
ELECTROLYTIC			5	50WV	20PF $\pm 10\%$
14~16	16WV	1000 μF	3	50WV	50PF $\pm 10\%$
17, 18	25WV	1000 μF	CERAMIC DISC		
13	160WV	22 μF	1, 2, 4	50WV	0.01 $\mu F \pm 80\%$
10~12	250WV	22 μF	L-INDUCTOR		
TC-TRIMMER CAPACITOR			2	RF CHOKE	250 μH
CERAMIC			1	FIX OUTPUT COIL	
1	ECV1ZW50P32	50PF	VFO UNIT		
L-INDUCTOR			PRINTED CIRCUIT BOARD PB-1056(A~Z)		
1, 2	RF CHOKE	4mH	Q-FET & TRANSISTOR		
X-CRYSTAL			3	TR.	2SC372Y
1	HC-13/U	100KHz	1, 2	FET	2SK19GR
NB UNIT			D-DIODE		
PRINTED CIRCUIT BOARD PB-1292(A~Z)			1	Varactor	1S145
Q-FET & TRANSISTOR			R-RESISTOR		
1, 6	TR.	2SC372Y	CARBON FILM		
4	TR.	2SC784R	4, 7	$\frac{1}{4}W$	100 $\Omega \pm 10\%$
2, 3	FET	2SK19GR	10	$\frac{1}{4}W$	270 $\Omega \pm 10\%$
5	FET	2SK34E	3, 6	$\frac{1}{4}W$	330 $\Omega \pm 10\%$
			8	$\frac{1}{4}W$	8.2K $\Omega \pm 10\%$

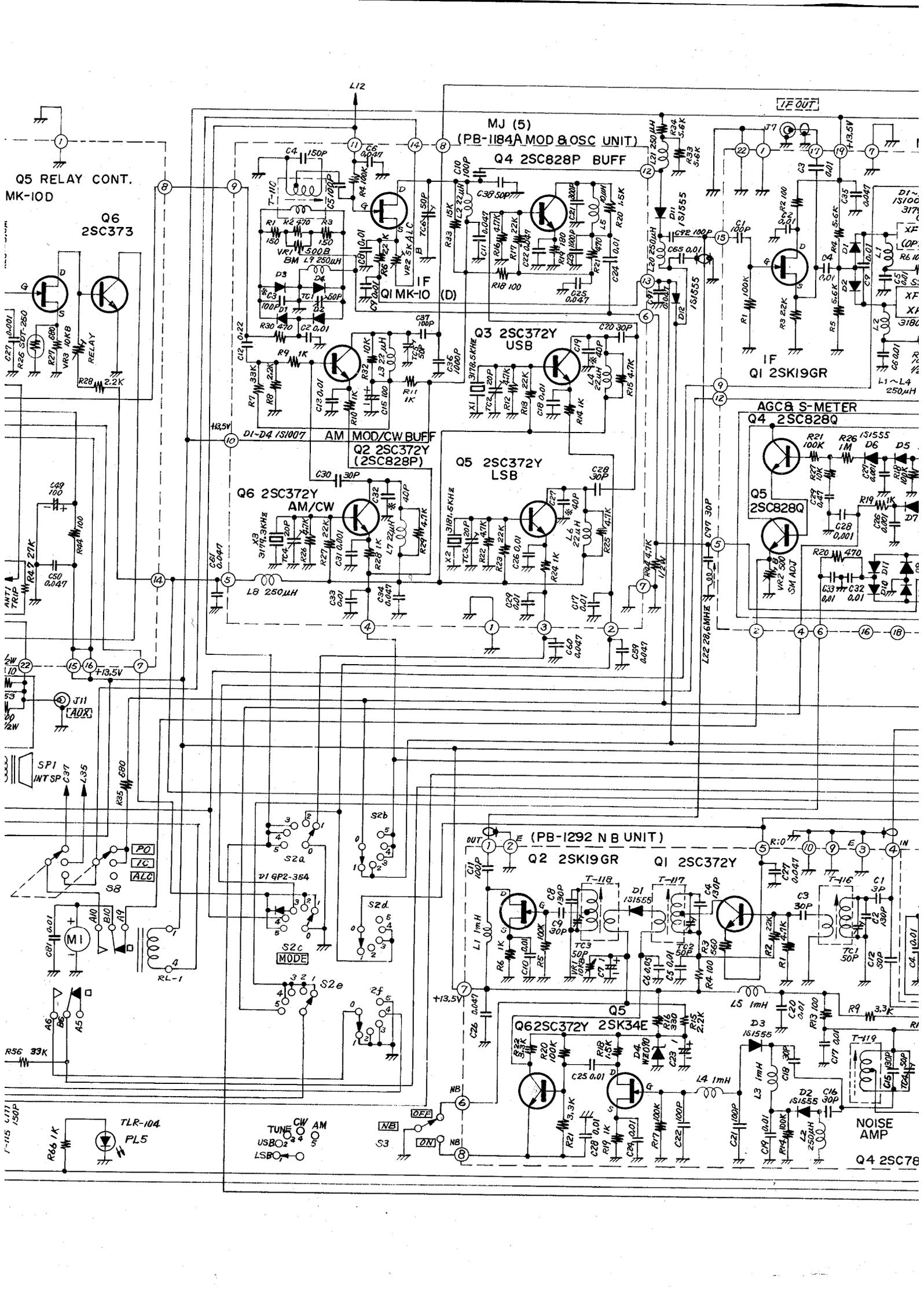
51, 62, 65, 81~83, 86, 87, 90, 118	50WV 0.01 μ F	+80% -20%	T-TRANSFORMER & CHOKE COIL	
			11	POWER TRANSFORMER
33, 38, 50, 52, 59~61, 66, 69~73, 85, 89, 91, 94, 95, 100, 103	50WV 0.047 μ F	+80% -20%	12	AF CHOKE 20mH 0.5A
			F-FUSE	
8, 14, 15, 20, 22	500WV 0.0047 μ F	+100% -0%	1	AC 5A(100~117V)3A(200~234V)
3, 19, 21, 101, 102	500WV 0.01 μ F	+100% -0%	2	DC 20A
74	1.4KV 0.001 μ F	+100% -0%	FH-FUSE HOLDER	
24	1.4KV 0.0047 μ F	+100% -0%	1	AC S-N1001
36, 75	1.4KV 0.01 μ F	+100% -0%	2	DC S-N1102
			RL-RELAY	
25	(RDA30) 3KV	150PF \pm 10%	1	AE3171-42
132	3KV	600PF \pm 10%	2	MX2P
CERAMIC FEED THRU				
30~32, 34, 35, 37, 39, 40, 67, 68, 84, 110	500WV 0.001 μ F	+100% -0%		
PLASTIC FILM			S-SWITCH	
140, 141	50WV 0.047 μ F	\pm 20%	1	ROTARY RS13-13-11(BAND)
18	50WV 0.22 μ F	\pm 20%	2	ROTARY ESRE365R20Z(MODE)
49	50WV 0.47 μ F	\pm 20%	4	ROTARY ESRE246R20Z(SELECT)
METALIZED PAPER			6	SEASAW WD3001 (POWER)
76	160WV 2.2 μ F	\pm 20%	5	SEASAW WD3201 (HEATER)
145	220VAC	1 μ F	3, 10	SLIDE SS-F22-08
ELECTROLYTIC			7~9	SLIDE SS-H23-08
142	16WV	1 μ F		
54, 144	16WV	10 μ F		
143	16WV	100 μ F		
63	16WV	220 μ F	X-CRYSTAL	
109	450WV	2.2 μ F	1 80M	HC-25/U 9.52MHz
77, 78	500WV	100 μ F	2 40M	HC-25/U 13.02MHz
VC-VARIABLE CAPACITOR			3 20M	HC-25/U 20.02MHz
1	(PLATE) AIR	RT18B300VC	4 15M	HC-25/U 27.02MHz
2	(LOADING)AIR	C123A129	5 11M	HC-25/U 33.02MHz
TC-TRIMMER CAPACITOR			6 10M-A	HC-25/U 34.02MHz
CERAMIC			7 10M-B	HC-25/U 34.52MHz
5	ECVIZW10P32	10PF	8 10M-C	HC-25/U 35.02MHz
1~4, 11~25	ECVIZW50P32	50PF	9 10M-D	HC-25/U 35.52MHz
7, 8, 9	MICA B-1PY	40PF	10 JJY/WWV	HC-25/U 16.02MHz
6, 31	B-2PY	100PF	11 160M	HC-25/U 7.52MHz
10, 26, 28, 29	B-7P	420PF		
27	AIR	TSN-150C	MJ-MULTI JACK	
PLASTIC FILM			1, 2, 6	3305-018-011 18 P
30	CTY12B	10PF	3, 4	3305-022-011 22P
L-INDUCTOR			5	3305-014-011 14P
12, 13, 16~18, 20, 21, 26, 31, 35, 38	RF CHOKE	250 μ H	7	3305-010-011 10P
3, 11, 14, 15, 36	RF CHOKE(TV-245)	250 μ H	PL-LAMP	
9	RF CHOKE	300 μ H	1, 2, 4	15V 0.15A
7	RF CHOKE(PLATE)	500 μ H	3	14V 40mA
2	RF CHOKE	1mH	5, 6	TLR-104
24	P.S. $\frac{1}{2}$ W56 Ω 0.3 ϕ	10TS	PLH-LAMP HOLDER	
1, 4, 37	P.S. $\frac{1}{2}$ W56 Ω 0.6 ϕ	4TS	1, 2	#001011
5, 6	P.S. 1W56 Ω 1.0 ϕ	4TS	3	B-1
8	TANK COIL		VS-TUBE SOCKET	
22	TRAP COIL		1	TS103C01
28	TRAP COIL		2, 3	S-B0703
29	TRAP COIL		J-RECEPTACLE & JACK	
32	TRAP COIL		1, 4, 5, 7, 8, 11, 16~18	CN-7017
33	TUNING COIL		2	S-G7616 (KEY)
25	L.P.FILTER COIL		10	S-G7814 (PHONE)
			3	FM-144 (MIC)
			6	JSO-239 (ANT)
			9	450AB12M(POWER)
T-TRANSFORMER & INDUCTOR			12	P2240 (SP)
101A	ANT COIL A		13	S-B0611 (EXT.VFO)
102	GRID COIL A		14	SA602B(ACC)
103	DRIVER COIL A		15	S-I6303 (FAN)
104	ANT COIL B			
105	DRIVER COIL B			
106	GRID COIL B			
107	5MHz TRAP COIL		M-METER	
111	6.36MHz TRAP COIL		1	MK-45
115	3.18MHz TRAP COIL			
112A	BAND PASS NETWORK			



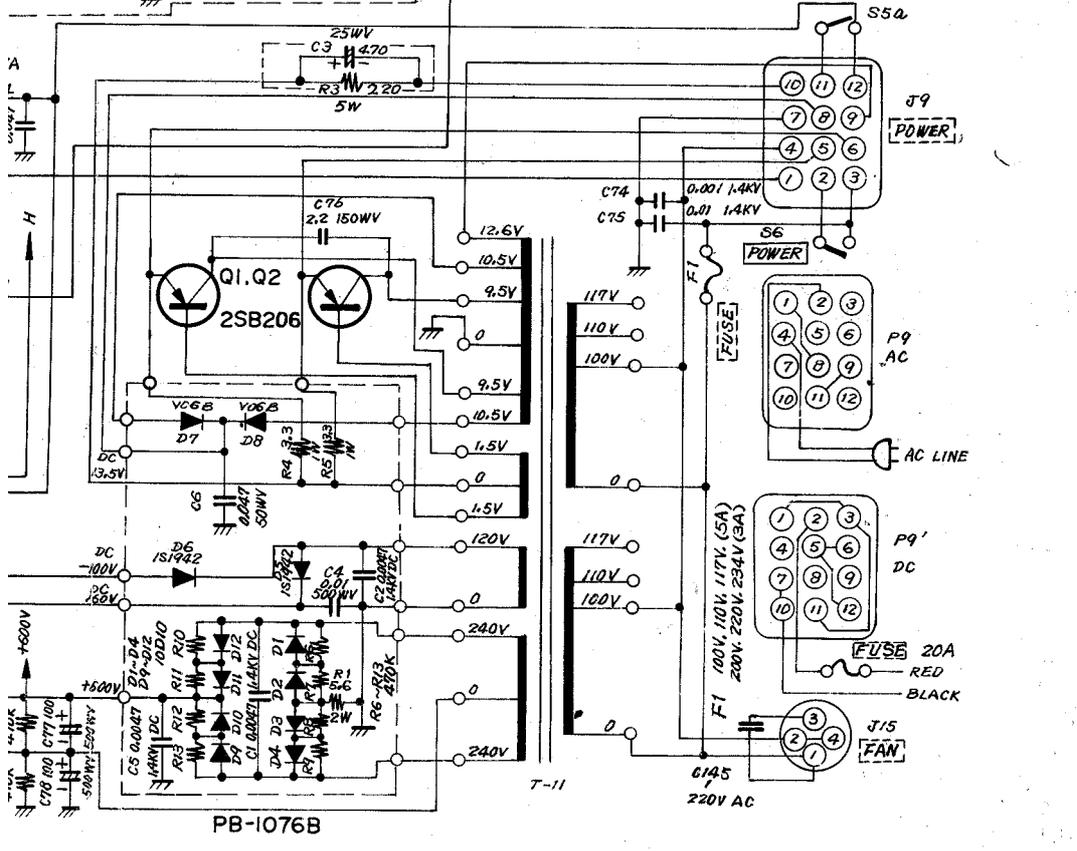
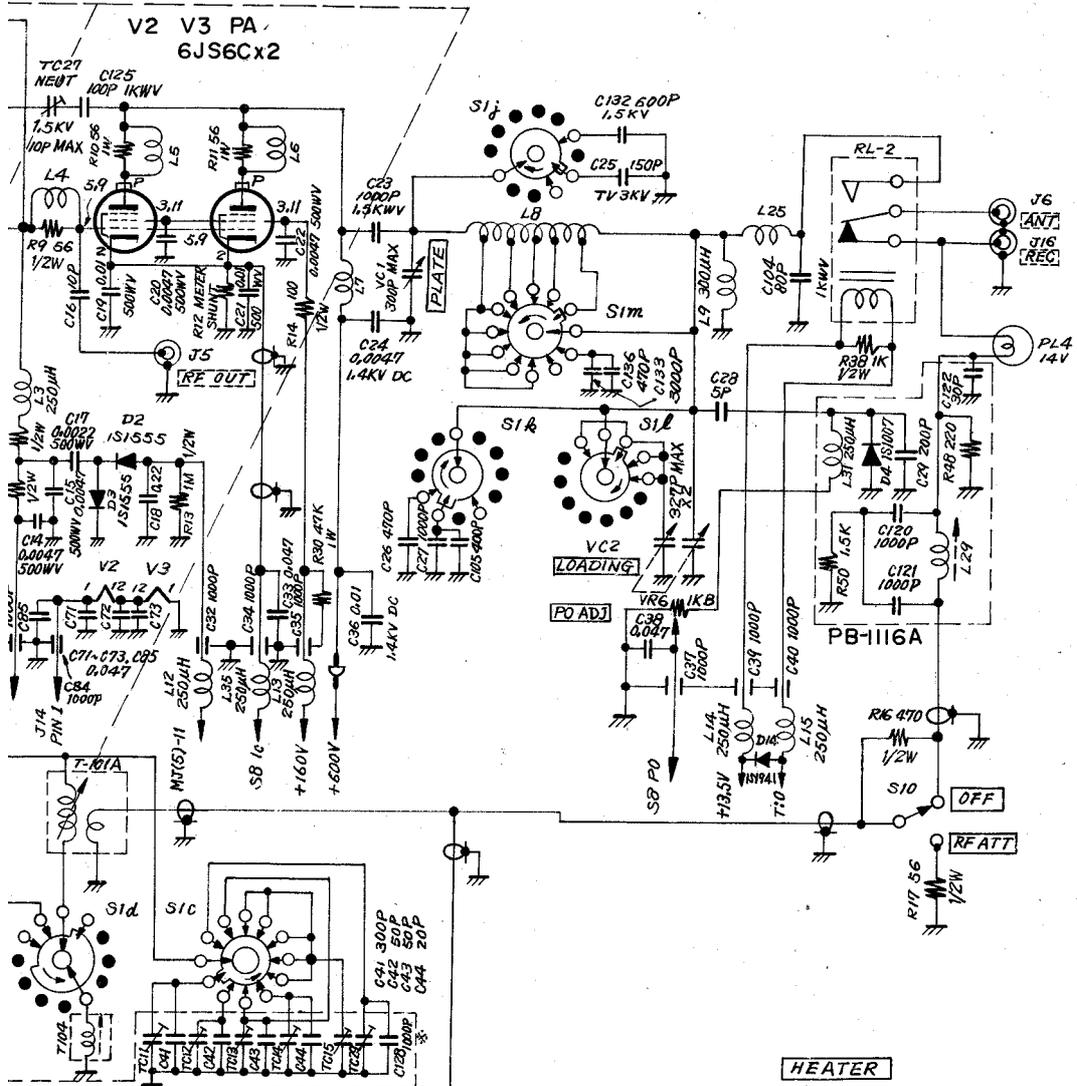
NOTES

1. ALL RESISTORS ARE IN 1/4W UNLESS OTHERWISE NOTED.
2. ALL CAPACITORS ARE IN μ F UNLESS OTHERWISE NOTED.
3. ALL ELECTROLYTIC CAPACITORS ARE 16WV UNLESS OTHERWISE NOTED.
- 4 * VALUE IS NOMINAL.





ECT



MJ ピン 番号	マルチコネクタ各端子の抵抗値							マルチコネクタ各端子の電圧														マルチコネクタ各端子の高周波電圧														
	1	2	3	4	5	6	7	1		2		3		4		5		6		7		1		2		3		4		5		6		7		
								R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	
1	E	E	E	E	E	E	∞	E	E	E	E	E	E	E	E	E	E	E	E	E	0	0	E	E	E	E	E	E	E	E	E	E	E	E	3180kHz 85dB	-
2	E	E	150	30k	0	10k	E	E	E	E	E	0	0	0	0	0	0	-70	-55	E	E	E	E	E	E	-	-	-	-	-	-	-	-	E	E	
3	300	0	10	0	∞	4k	E	6.0	6.0	0	0	13.0	12.5	0	0	0.7	0.7	-18	0	E	E	*3	*3	3180kHz 85dB	0	-	-	-	-	-	-	-	E	E		
4	3k	E	∞	*	10k	10k	0	0.5	0.5	E	E	0	0	0	0	8.5	8.5	-20	-3.5	0	0	*2	*2	E	E	-	-	-	-	-	-	-	-	3180kHz 85dB	-	
5	300	∞	0	∞	200	30k	0	5.5	5.5	0	0	0	0	0	0	6.0	6.0	-150	-140	0	13.0	-	-	-	0	0.6	0	-	-	-	-	-	-	-	-	
6	200	E	1k	E	5	50k	0	6.0	6.0	E	E	0	0	E	E	0	0	170	170	0	0	-	-	E	E	-	-	E	E	1	1	-	-	-	-	
7	E	10	E	0	E	3k	10	E	E	13.0	12.5	E	E	0	0	E	E	2.7	2.7	13.5	13.5	E	E	-	-	E	E	-	-	E	E	-	-	-	-	
8	0	E	0	1k	5k	6k	100k	0	0	E	E	0	11.5	0	0	0	0	0.6	2.7	1.0	1.0	14MHz 48dB	-	E	E	-	-	-	-	-	-	-	-	-	-	
9	2.5k	120	10k	10k	1k	120	E	8.0	13.0	12.0	0	9.0	9.0	9.0	9.0	0	0	12.5		E	E	-	-	-	-	-	-	-	-	-	-	-	-	E	E	
10	*	E	3k	50k	10	0	E	0	11.5	E	E	6.5	0.35	1.5	1.5	13.0	12.5	0	11.5	E	E	-	-	E	E	3180kHz 70dB	0.01	-	-	-	-	-	-	E	E	
11	100	∞	10	E	1M	3k	/	13.0	12.5	0	0	13.0	12.5	E	E	0	0	2.5	2.5	/	/	14MHz 60dB	1	0.08	0.06	-	-	E	E	-	-	-	-	/	/	
12	120	E	1k	50k	3k	10	/	12.5	0	E	E	0.7	0.7	9.0	9.0	6.6	0.3	13.5	13.0	/	/	-	-	E	E	-	-	-	-	-	0.1	-	-	/	/	
13	120	0	3k	∞	1.2k	200	/	12.0	0	0	11.5	8.0	13.0	0	0	12.5	0	6.0	6.0	/	/	-	0.06	-	-	-	-	-	-	-	-	-	-	/	/	
14	10	E	E	200	700	10	/	13.0	12.5	E	E	E	E	6.0	6.0	12.5	0.3	13.0	12.5	/	/	-	-	-	E	E	E	-	-	-	-	-	-	/	/	
15	0	100	∞	10	/	50k	/	0	0	13.0	12.5	0	0	13.0	12.5	/	/	0	0	/	/	0.3	0.8	5720kHz 66dB	0.3	3180kHz 83dB	0.06	-	-	/	/	-	-	/	/	
16	0	100	∞	10	/	0	/	0	11.5	13.0	12.5	0	0	13.0	12.5	/	/	0	0	/	/	-	-	5720kHz 56dB	0.1	-	-	-	-	/	/	-	-	/	/	
17	100	E	∞	*	/	∞	/	13.0	12.5	E	E	0	0	0	0	/	/	0	0	/	/	5720kHz 70dB	0.3	E	E	3180kHz 78dB	0.03	-	-	/	/	-	-	/	/	
18	E	E	∞	∞	/	E	/	E	E	E	E	0	0	E	E	/	/	E	E	/	/	E	E	E	E	-	-	E	E	/	/	E	E	/	/	
19	/	/	10	*	/	/	/	/	/	/	/	13.0	12.5	E	E	/	/	/	/	/	/	/	/	/	/	-	-	E	E	/	/	/	/	/	/	
20	/	/	120	E	/	/	/	/	/	/	/	12.5	0	E	E	/	/	/	/	/	/	/	/	/	/	-	-	-	-	/	/	/	/	/	/	
21	/	/	200	E	/	/	/	/	/	/	/	6.0	6.0	E	E	/	/	/	/	/	/	/	/	/	/	-	-	-	-	/	/	/	/	/	/	
22	/	/	E	*	/	/	/	/	/	/	/	E	E	0	0	/	/	/	/	/	/	/	/	/	/	E	E	-	-	/	/	/	/	/	/	

抵抗値は VTVM のリードの極性によって
差があります。この表の抵抗値は高い方
を示します。

MODEスイッチ：USBにて測定(VTVM使用) 単位(V)
R：受信時(PTT) T：送信時(MOX)

MODEスイッチ：USB, BAND：20m 単位(V)
R：受信時(PTT)S-9 振れるのに必要なSGの出力電圧(dB)
T：送信時(MOX) 1kHz単信号を加え100W出力時の高周波電圧(V)

パーツリストについてのご注意

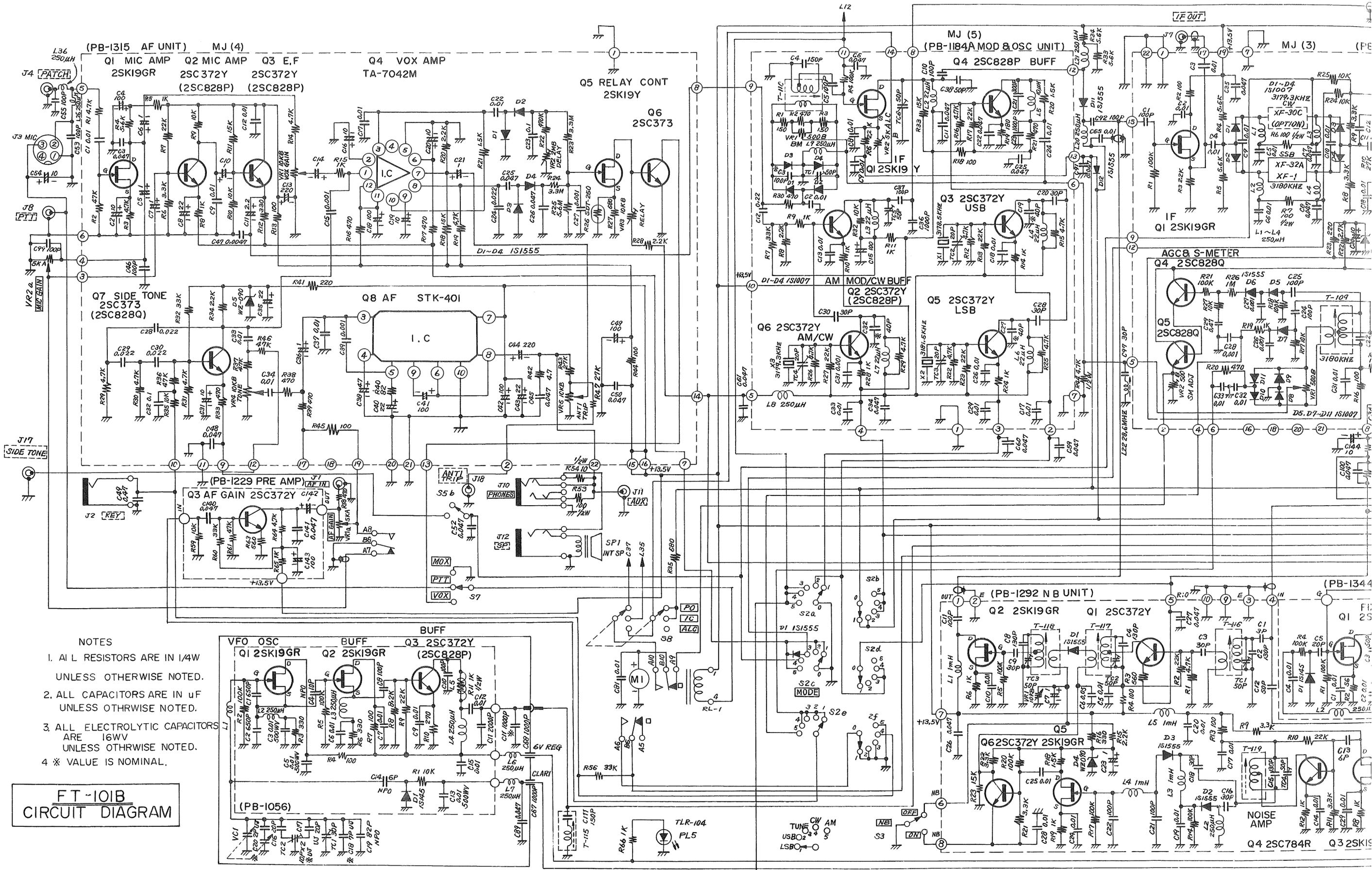
本機の部品番号はユニットごとに1から始まっています。従って部品についてご照会いただく場合は、ユニット名と部品番号をあわせてご指定ください。

RF UNIT				C-CAPACITOR			
PRINTED CIRCUIT BOARD PB-1181(A~Z)				DIPPED MICA			
Q-FET & TRANSISTOR				6, 19	50 WV	20PF ± 10%	
4	TR.	2SC372Y		1, 8	50 WV	40PF ± 10%	
5	TR.	2SC373		8	50 WV	100PF ± 10%	
3	TR.	2SC784R		2	50 WV	470PF ± 10%	
2	FET	2SK19GR		CERAMIC DISC			
1	FET	3SK40M		7	50 WV	0.001 μF	+ 80% - 20%
D-DIODE				3~5, 9, 11, 13	50 WV	0.01 μF	+ 80% - 20%
1, 2	Si.	1S1555		17	50 WV	0.047 μF	+ 80% - 20%
R-RESISTOR				CERAMIC FEED THRU			
CARBON FILM				14~16	500 WV	0.001 μF	+ 100% - 0%
22	1/4 W	56 Ω ± 10%		ELECTROLYTIC			
23	1/4 W	100 Ω ± 10%		18	16 WV	1 μF	
16, 24	1/4 W	220 Ω ± 10%		TC-TRIMMER CAPACITOR			
6	1/4 W	330 Ω ± 10%		CERAMIC			
10, 19	1/4 W	470 Ω ± 10%		1~3	ECVIZW50P32	50 PF	
11	1/4 W	560 Ω ± 10%		L-INDUCTOR			
9, 13	1/4 W	1 KΩ ± 10%		1	BPF-A		
7	1/4 W	1.8 KΩ ± 10%		2	BPF-B		
8	1/4 W	2.2 KΩ ± 10%		3	BPF-C		
17, 20	1/4 W	3.3 KΩ ± 10%		34	RF CHOKE	1.95 μH	
21	1/4 W	8.2 KΩ ± 10%		4, 8	RF CHOKE	250 μH	
14, 18	1/4 W	15 KΩ ± 10%		T-TURNFORMER & INDUCTOR			
2	1/4 W	22 KΩ ± 10%		112A	IF TRANSFORMER		
4	1/4 W	82 KΩ ± 10%		113	TRAP COIL		
1, 3, 5, 12	1/4 W	100 KΩ ± 10%		X-CRYSTAL			
VR-VARIABLE RESISTOR				1	HC-18/U	6360 KHz	
1	TR-11R	5 KΩ B		IF UNIT			
C-CAPACITOR				PRINTED CIRCUIT BOARD PB-1183(A~Z)			
DIPPED MICA				Q-FET, IC & TRANSISTOR			
17	50 WV	6PF ± 0.5PF		2	TR.	2SC784R	
5	50 WV	50PF ± 10%		4, 5	TR.	2SC828Q	
1, 11	50 WV	100PF ± 10%		3	IC	CA3053	
CERAMIC DISC				1	FET	2SK19GR	
3	50 WV	0.001 μF	+ 80% - 20%	D-DIODE			
2, 4, 7~10, 12~16,	50 WV	0.01 μF	+ 80% - 20%	1~5, 7~11	Ge.	1S1007	
6, 18	50 WV	0.047 μF	+ 80% - 20%	6	Si.	1S1555	
ELECTROLYTIC				12	Zener	WZ-110	
19	16W	47 μF		R-RESISTOR			
L-INDUCTOR				CARBON FILM			
1, 2	RF CHOKE	1 mH		2, 13, 16	1/4 W	100 Ω ± 10%	
MIXER UNIT				23	1/4 W	220 Ω ± 10%	
PRINTED CIRCUIT BOARD PB-1082(A~Z) PB-1180(A~Z)				20	1/4 W	470 Ω ± 10%	
Q-FET & TRANSISTOR				12, 15, 19	1/4 W	1 KΩ ± 10%	
1	TR.	2SC372Y		3, 14	1/4 W	2.2 KΩ ± 10%	
2	FET	3SK40M		8, 9, 22	1/4 W	3.3 KΩ ± 10%	
D-DIODE				11	1/4 W	3.9 KΩ ± 10%	
1	Si.	1S1555		4, 5	1/4 W	5.6 KΩ ± 10%	
R-RESISTOR				17, 24, 25, 27	1/4 W	10 KΩ ± 10%	
CARBON FILM				10	1/4 W	27 KΩ ± 10%	
12	1/4 W	10 Ω ± 10%		1, 18, 21	1/4 W	100 KΩ ± 10%	
5, 7	1/4 W	100 Ω ± 10%		CARBON COMPOSITION			
13	1/4 W	470 Ω ± 10%		26	1/4 W	1 MΩ ± 10%	
3, 16, 17	1/4 W	1 KΩ ± 10%		6, 7	1/2 W	100 Ω ± 10%	
2	1/4 W	4.7 KΩ ± 10%		VR-VARIABLE RESISTOR			
14, 15	1/4 W	5.6 KΩ ± 10%		1	TR12R	500 Ω B	
10	1/4 W	10 KΩ ± 10%		2	TR11R	500 Ω B	
4, 6	1/4 W	15 KΩ ± 10%		C-CAPACITOR			
11	1/4 W	22 KΩ ± 10%		DIPPED MICA			
1	1/4 W	27 KΩ ± 10%		1, 24, 25	50 WV	100PF ± 10%	
8	1/4 W	100 KΩ ± 10%					
9	1/4 W	220 KΩ ± 10%					

15, 22	50WV	150PF ±10%	15, 27, 39	50WV	0.001μF ±20%
11, 17	50WV	470PF ±10%	1, 9, 12, 17, 22, 33, 34	50WV	0.01 μF ±20%
CERAMIC DISC			24, 28 ~30	50WV	0.022μF ±20%
26~28	50WV	0.001μF +80% -20%	3, 25, 26, 45, 48, 50	50WV	0.047μF ±20%
2~6, 9, 10, 12, 13, 18, 20, 21, 23, 31~34	50WV	0.01 μF +80% -20%	23, 32	50WV	0.1 μF ±20%
7, 8, 14, 16, 19, 35	50WV	0.047μF +80% -20%	11	50WV	2.2 μF ±20%
			ELECTROLYTIC		
			5~7, 10, 14, 21, 36	16WV	1μF
			2, 16, 19, 20, 31	16WV	10μF
PLASTIC FILM			8, 35, 40, 43	16WV	22μF
29	50WV	0.47 μF ±20%	38	16WV	47μF
ELECTROLYTIC			4, 18, 41, 42, 49	16WV	100μF
30	16WV	10μF	13, 44	16WV	220μF
L-INDUCTOR					
1~4	RF CHOKE	250μH	MOD. & OSC UNIT		
T-TRANSFORMER & INDUCTOR			PRINTED CIRCUIT BOARD PB-1184(A~Z)		
108	IF TRANSFORMER		Q-FET & TRANSISTOR		
109	IF TRANSFORMER(DETECTOR)		2, 3, 5, 6	TR.	2SC372Y
XF-CRYSTAL FILTER			4	TR.	2SC828P
1	XF-32A	SSB	1	FET.	MK-10D
2	XF-30C	CW(OPTION)	D-DIODE		
			1~4	Ge.	1S1007
			R-RESISTOR		
AF UNIT			CARBON FILM		
PRINTED CIRCUIT BOARD PB-1315(A~Z)			18	¼W	100 Ω ±10%
Q-FET, IC & TRANSISTOR			1, 3	¼W	150 Ω ±10%
2, 3	TR.	2SC372Y	19	¼W	180 Ω ±10%
6, 7	TR.	2SC373	2, 21, 30	¼W	470 Ω ±10%
5	FET	MK-10D	9~11, 14, 24, 28	¼W	1 KΩ ±10%
1	FET	2SK19GR	20	¼W	1.5KΩ ±10%
8	IC	STK401	6, 8	¼W	2.2KΩ ±10%
4	IC	TA7042M	12, 15, 16, 22, 25, 26, 29	¼W	4.7KΩ ±10%
D-DIODE			32	¼W	10 KΩ ±10%
1~4	Si.	1S1555	33	¼W	15 KΩ ±10%
5	Zener	WZ-090	13, 17, 23, 27	¼W	22 KΩ ±10%
R-RESISTOR			7	¼W	33 KΩ ±10%
			4	¼W	100 KΩ ±10%
CARBON FILM					
42	¼W	4.7Ω ±10%			
40	¼W	82 Ω ±10%			
13, 44, 45	¼W	100 Ω ±10%			
41	¼W	220 Ω ±10%			
12	¼W	330 Ω ±10%			
16, 17, 33, 38, 39	¼W	470 Ω ±10%			
27	¼W	680 Ω ±10%			
5, 8, 15	¼W	1 KΩ ±10%			
21	¼W	1.5KΩ ±10%			
20, 28, 34	¼W	2.2KΩ ±10%			
6	¼W	3.3KΩ ±10%			
1, 3, 14, 19, 29~31	¼W	4.7KΩ ±10%			
4	¼W	5.6KΩ ±10%			
9, 10, 35	¼W	10 KΩ ±10%			
11, 18	¼W	15 KΩ ±10%			
7	¼W	22 KΩ ±10%			
43, 47	¼W	27 KΩ ±10%			
32	¼W	33 KΩ ±10%			
2, 36, 37, 46	¼W	47 KΩ ±10%			
22	¼W	470 KΩ ±10%			
			VR-VARIABLE RESISTOR		
			1	TR11R	500ΩB
			2	TR11R	5KΩB
			C-CAPACITOR		
			DIPPED MICA		
			20, 28, 30	50WV	30PF ±10%
			19, 27, 32	50WV	40PF ±10%
			38	50WV	50PF ±10%
			5, 10, 37	50WV	100PF ±10%
			4	50WV	150PF ±10%
			21	50WV	300PF ±10%
			23, 36	50WV	1000PF ±10%
			CERAMIC DISC		
			31	50WV	0.001μF +80% -20%
			2, 8, 9, 13, 17, 18, 24, 26, 29, 33	50WV	0.01 μF +80% -20%
			6, 11, 22, 25, 34	50WV	0.047μF +80% -20%
			PLASTIC FILM		
			12	50WV	0.22 μF ±20%
			ELECTROLYTIC		
			15	16WV	100μF
CARBON COMPOSITION					
23, 24	¼W	3.3MΩ ±10%			
25	¼W	5.6MΩ ±10%			
26	THERMISTOR	SDT-250			
VR-VARIABLE RESISTOR			TC-TRIMMER CAPACITOR		
3, 4	TR11R	10KΩB	CERAMIC		
1, 5	V160KRZ-I	10KΩB	2~4	ECVIZW20P40	20PF
2	V160KRZ-I	2MΩB	1, 5, 6	ECVIZW50P40	50PF
C-CAPACITOR			L-INDUCTOR		
DIPPED MICA			5	RF CHOKE	10μH
46	50WV	100PF ±10%	2~4, 6, 7	RF CHOKE	22μH
PLASTIC FILM			8, 9	RF CHOKE	250μH
47	50WV	0.0047μF ±20%			

T-TRANSFORMER		D-DIODE	
110	IF TRANSFORMER	1-3	Si IS1555
X-CRYSTAL		4	Zener WZ090
1	HC-6/U 3178.5KHz(USB)	R-RESISTOR	
2	HC-6/U 3181.5KHz(LSB)	CARBON FILM	
3	HC-6/U 3179.3KHz(CW/AM)	4, 13	$\frac{1}{4}W$ 100 $\Omega \pm 10\%$
REG & CALIB UNIT		16	$\frac{1}{4}W$ 330 $\Omega \pm 10\%$
PRINTED CIRCUIT BOARD PB-1314(A~Z)		3	$\frac{1}{4}W$ 560 $\Omega \pm 10\%$
Q-TRANSISTOR		6, 8, 12, 19	$\frac{1}{4}W$ 1 K $\Omega \pm 10\%$
6	TR. 2SC372Y	18	$\frac{1}{4}W$ 1.5K $\Omega \pm 10\%$
1~4	TR. 2SC735Y	15	$\frac{1}{4}W$ 2.2K $\Omega \pm 10\%$
5	TR. 2SD313	9, 11, 21, 22	$\frac{1}{4}W$ 3.3K $\Omega \pm 10\%$
D-DIODE		1	$\frac{1}{4}W$ 4.7K $\Omega \pm 10\%$
2	Zener IS993	2, 10	$\frac{1}{4}W$ 22 K $\Omega \pm 10\%$
1, 5, 6	Si IS1555	5, 7, 14, 17, 20	$\frac{1}{4}W$ 100 K $\Omega \pm 10\%$
3	Zener WZ-090	VR-VARIABLE RESISTOR	
R-RESISTOR		1	TRIIR 10K Ω B
CARBON FILM		C-CAPACITOR	
3, 10	$\frac{1}{4}W$ 100 $\Omega \pm 10\%$	DIPPED MICA	
22	$\frac{1}{4}W$ 220 $\Omega \pm 10\%$	1	50WV 3PF $\pm 0.5PF$
17, 19,	$\frac{1}{4}W$ 330 $\Omega \pm 10\%$	13	50WV 6PF $\pm 1PF$
26	$\frac{1}{4}W$ 470 $\Omega \pm 10\%$	3, 9, 16, 18	50WV 30PF $\pm 10\%$
18	$\frac{1}{4}W$ 1 K $\Omega \pm 10\%$	12	50WV 50PF $\pm 10\%$
12	$\frac{1}{4}W$ 1.5K $\Omega \pm 10\%$	11, 21, 22	50WV 100PF $\pm 10\%$
20	$\frac{1}{4}W$ 2.2K $\Omega \pm 10\%$	2, 4, 8, 15	50WV 130PF $\pm 10\%$
4, 7, 11	$\frac{1}{4}W$ 4.7K $\Omega \pm 10\%$	CERAMIC DISC	
1, 8, 13, 15, 24	$\frac{1}{4}W$ 10 K $\Omega \pm 10\%$	5, 10, 14, 17, 19, 20, 24,	50WV 0.01 μ F $\pm 80\%$ $- 20\%$
25	$\frac{1}{4}W$ 15 K $\Omega \pm 10\%$	25, 28, 29	50WV 0.047 μ F $\pm 80\%$ $- 20\%$
5	$\frac{1}{4}W$ 27 K $\Omega \pm 10\%$	ELECTROLYTIC	
6	$\frac{1}{4}W$ 33 K $\Omega \pm 10\%$	7, 23	16WV 1 μ F
14	$\frac{1}{4}W$ 47 K $\Omega \pm 10\%$	TC-TRIMMER CAPACITOR	
2, 9	$\frac{1}{4}W$ 100 K $\Omega \pm 10\%$	CERAMIC	
CARBON COMPOSITION		1~4	ECVIZW50P40 50PF
16	2W 6.8K $\Omega \pm 10\%$	L-INDUCTOR	
VR-VARIABLE RESISTOR		2	RF CHOKE 250 μ H
4	TRIIR 500 Ω B	1, 3~5	RF CHOKE 1mH
3	TRIIR 1K Ω B	T-TRANSFORMER	
1	TRIIR 10K Ω B	116~119 IF TRANSFORMER R124129	
2	VI60KRZ-1 10K Ω B	FIX UNIT	
C-CAPACITOR		PRINTED CIRCUIT BOARD PB-1344(A~Z)	
DIPPED MICA		Q-FET	
5, 6, 21	50WV 30PF $\pm 10\%$	1 FET MK10E	
9	50WV 40PF $\pm 10\%$	D-DIODE	
20	50WV 50PF $\pm 10\%$	1 Varactor IS145	
2	50WV 100PF $\pm 10\%$	R-RESISTOR	
1	50WV 250PF $\pm 10\%$	CARBON FILM	
7, 8	50WV 1000PF $\pm 10\%$	2	$\frac{1}{4}W$ 56 $\Omega \pm 10\%$
3	50WV 2000PF $\pm 10\%$	3	$\frac{1}{4}W$ 100 $\Omega \pm 10\%$
CERAMIC DISC		1, 4	$\frac{1}{4}W$ 100K $\Omega \pm 10\%$
4, 19	50WV 0.01 μ F $\pm 80\%$ $- 20\%$	C-CAPACITOR	
PLASTIC FILM		DIPPED MICA	
24	250WV 0.047 μ F $\pm 20\%$	5	50WV 20PF $\pm 10\%$
ELECTROLYTIC		3	50WV 50PF $\pm 10\%$
14~16	16WV 1000 μ F	CERAMIC DISC	
17, 18	25WV 1000 μ F	1, 2, 4	50WV 0.01 μ F $\pm 80\%$ $- 20\%$
13	160WV 22 μ F	L-INDUCTOR	
10~12	250WV 22 μ F	2	RF CHOKE 250 μ H
TC-TRIMMER CAPACITOR		1	FIX OUTPUT COIL
CERAMIC		VFO UNIT	
1	ECVIZW50P32 50PF	PRINTED CIRCUIT BOARD PB-1056(A~Z)	
L-INDUCTOR		Q-FET & TRANSISTOR	
1, 2	RF CHOKE 4mH	3	TR. 2SC372Y
X-CRYSTAL		1, 2	FET 2SK19GR
1	HC-13/U 100KHz	D-DIODE	
NB UNIT		1 Varactor IS145	
PRINTED CIRCUIT BOARD PB-1292(A~Z)		R-RESISTOR	
Q-FET & TRANSISTOR		CARBON FILM	
1, 6	TR. 2SC372Y	4, 7	$\frac{1}{4}W$ 100 $\Omega \pm 10\%$
4	TR. 2SC784R	10	$\frac{1}{4}W$ 270 $\Omega \pm 10\%$
2, 3	FET 2SK19GR	3, 6	$\frac{1}{4}W$ 330 $\Omega \pm 10\%$
5	FET 2SK34E	8	$\frac{1}{4}W$ 8.2K $\Omega \pm 10\%$

1	$\frac{1}{4}$ W	10	$K\Omega \pm 10\%$	1~3, 8, 11~13	Si.	IS1555
9	$\frac{1}{4}$ W	22	$K\Omega \pm 10\%$	14	Si.	IS1941
2, 5	$\frac{1}{4}$ W	100	$K\Omega \pm 10\%$	9	Zener	WZ-090
CARBON COMPOSITION				R-RESISTOR		
11(L5)	$\frac{1}{2}$ W	1	$K\Omega \pm 10\%$	CARBON FILM		
				48	$\frac{1}{4}$ W	220 $\Omega \pm 10\%$
				22	$\frac{1}{4}$ W	330 $\Omega \pm 10\%$
				18	$\frac{1}{4}$ W	470 $\Omega \pm 10\%$
				26, 62	$\frac{1}{4}$ W	560 $\Omega \pm 10\%$
C-CAPACITOR				64, 65, 68	$\frac{1}{4}$ W	1K $\Omega \pm 10\%$
DIPPED MICA				50	$\frac{1}{4}$ W	1.5K $\Omega \pm 10\%$
16	50WV	20PF	$\pm 10\%$	61, 63	$\frac{1}{4}$ W	4.7K $\Omega \pm 10\%$
8, 10	50WV	100PF	$\pm 10\%$	23, 24, 33, 34	$\frac{1}{4}$ W	5.6K $\Omega \pm 10\%$
1, 2	50WV	650PF	$\pm 10\%$	25, 59	$\frac{1}{4}$ W	10 K $\Omega \pm 10\%$
11	50WV	1000PF	$\pm 10\%$	60	$\frac{1}{4}$ W	33K $\Omega \pm 10\%$
11	50WV	2000PF	$\pm 10\%$	CARBON COMPOSITION		
CERAMIC DISC				54	$\frac{1}{2}$ W	10 $\Omega \pm 10\%$
6, 7, 9, 12, 15	50WV	0.01 μ F	$\begin{matrix} +80\% \\ -20\% \end{matrix}$	4, 9, 17, 39, 69	$\frac{1}{2}$ W	56 $\Omega \pm 10\%$
3, 5, 13	500WV	0.01 μ F	$\begin{matrix} +100\% \\ -0\% \end{matrix}$	14, 51, 53, 55	$\frac{1}{2}$ W	100 $\Omega \pm 10\%$
CERAMIC TC				16	$\frac{1}{2}$ W	470 $\Omega \pm 10\%$
14	NP0	6PF	$\pm 0.5PF$	35	$\frac{1}{2}$ W	680 $\Omega \pm 10\%$
4	NP0	10PF	$\pm 10\%$	7, 38, 66	$\frac{1}{2}$ W	1 K $\Omega \pm 10\%$
19	NP0	82PF	$\pm 10\%$	6, 67	$\frac{1}{2}$ W	2.2K $\Omega \pm 10\%$
20	N750	2PF	$\pm 0.5PF$	2	$\frac{1}{2}$ W	3.3K $\Omega \pm 10\%$
18	N750	7PF	$\pm 0.5PF$	44	$\frac{1}{2}$ W	4.7K $\Omega \pm 10\%$
17	N750	20PF	$\pm 10\%$	19, 20	$\frac{1}{2}$ W	5.6K $\Omega \pm 10\%$
				8	$\frac{1}{2}$ W	10 K $\Omega \pm 10\%$
				36, 56	$\frac{1}{2}$ W	33 K $\Omega \pm 10\%$
				3	$\frac{1}{2}$ W	47 K $\Omega \pm 10\%$
				28, 29	$\frac{1}{2}$ W	470 K $\Omega \pm 10\%$
VC-VARIABLE CAPACITOR				13	$\frac{1}{2}$ W	1 M $\Omega \pm 10\%$
1	AIR	B521A112		10, 11	1 W	56 $\Omega \pm 10\%$
TC-TRIMMER CAPACITOR				METALIC FILM		
1	AIR	TSN150C30PF		30	1 W	47 K $\Omega \pm 10\%$
2	AIR	TSN170C10PF $\times 2$		5	3 W	5.1K $\Omega \pm 10\%$
L-INDUCTOR				40	5 W	1.5K $\Omega \pm 10\%$
1	OSCILLATOR COIL			37	5 W	18 K $\Omega \pm 10\%$
2~4, 6, 7	RF CHOKE		250 μ H	WIRE WOUND		
5(R11)	RF CHOKE			METER SHUNT		
				12		
RECTIFIER UNIT				VR-VARIABLE RESISTOR		
PRINTED CIRCUIT BOARD PB-1076(A~Z)				3	EVCBOQS20B13	1K Ω B
D-DIODE				6	EVHBOAS15B13	1K Ω B
5, 6	Si.	1S1942		1	EVKA2AF02314	5K Ω A/1K Ω B
1~4, 9~12	Si.	10D10		2	EVKA2AF01339	5K Ω A/5K Ω B
7, 8	Si.	V06B		4	TR-11R	500 Ω B
R-RESISTOR				C-CAPACITOR		
CARBON FILM				DIPPED MICA		
6~13	$\frac{1}{4}$ W	470	$K\Omega \pm 10\%$	123	500WV	2PF $\pm 0.5PF$
CARBON COMPOSITION				134	500WV	3PF $\pm 0.5PF$
4, 5	1 W	3.3 $\Omega \pm 10\%$		28	500WV	5PF $\pm 0.5PF$
1	2 W	5.6 $\Omega \pm 10\%$		1, 16, 98, 107	500WV	10PF $\pm 10\%$
METALIC FILM				44	500WV	20PF $\pm 10\%$
3	5W	220 $\Omega \pm 10\%$		97, 106, 122	500WV	30PF $\pm 10\%$
				5, 10, 42, 43, 47	500WV	50PF $\pm 10\%$
				135	500WV	60PF $\pm 10\%$
				48, 53, 55, 92, 99	500WV	100PF $\pm 10\%$
C-CAPACITOR				46, 111	500WV	150PF $\pm 10\%$
CERAMIC DISC				29	500WV	200PF $\pm 10\%$
6	50WV	0.047 μ F	$\begin{matrix} +80\% \\ -20\% \end{matrix}$	9, 127	500WV	250PF $\pm 10\%$
4	500WV	0.01 μ F	$\begin{matrix} +100\% \\ -0\% \end{matrix}$	4	500WV	270PF $\pm 10\%$
1, 2, 5	1.4KV	0.0047 μ F	$\begin{matrix} +100\% \\ -0\% \end{matrix}$	41, 45	500WV	300PF $\pm 10\%$
ELECTROLYTIC				105, 108	500WV	400PF $\pm 10\%$
3	25WV	470 μ F		2, 26, 136	500WV	470PF $\pm 10\%$
				7, 27, 120, 121,	500WV	1000PF $\pm 10\%$
				128~131		
MAIN CHASSIS				17	500WV	2200PF $\pm 10\%$
V-VACUUM TUBE				133	500WV	3000PF $\pm 10\%$
1	12BY7A			MOULDED MICA		
2, 3	6JS6C			13, 104	1KWV	80PF $\pm 10\%$
Q-TRANSISTOR				125	1KWV	100PF $\pm 10\%$
1, 2	TR.	2SB206		11	1KWV	200PF $\pm 10\%$
3	TR.	2SC372Y		23	1.5KWV	1000PF $\pm 10\%$
D-DIODE				CERAMIC DISC		
4, 7	Ge.	IS1007				



NOTES

1. ALL RESISTORS ARE IN 1/4W UNLESS OTHERWISE NOTED.
2. ALL CAPACITORS ARE IN μ F UNLESS OTHERWISE NOTED.
3. ALL ELECTROLYTIC CAPACITORS ARE 16VW UNLESS OTHERWISE NOTED.
4. * VALUE IS NOMINAL.

**FT-101B
CIRCUIT DIAGRAM**

